



650V / 16A

ACC016H06DC

SiC Schottky Barrier Diode

ACTRON TECHNOLOGY CORP.

Features

- Shorter recovery time
- High speed switching
- High surge current capability
- Enabling higher frequency and increased power density
- System efficiency improvement
- System cost and size savings due to the reduced cooling requirements

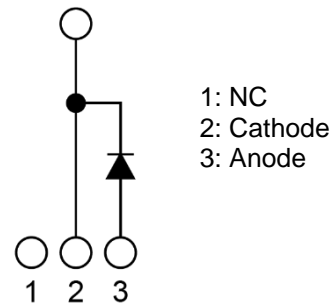
Outline (TO247-3L)



Applications

- Power Factor Correction in SMPS
- Solar inverter
- Uninterruptible Power Supply
- Motor Drives
- Data Center

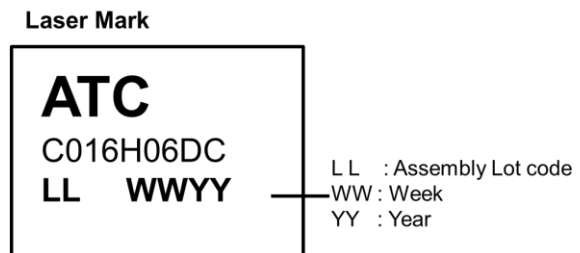
Circuit Diagram



Mechanical Characteristics

- TO247-3L package
- Halogen Free
- Pb free lead plating ; RoHS compliant
- Packaging: Tube

Marking Diagram





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Parameter and Specification

Absolute Maximum Rating⁽¹⁾

Parameter	Symbol	Condition	Value	Unit
Repetitive peak reverse voltage	V_{RM}	$T_c=25^{\circ}C$	650	V
Continue forward current	I_F	$T_c=135^{\circ}C$	16	A
Surge non-repetitive forward current , sine half-wave	I_{FSM}	$T_c=25^{\circ}C, t_p=10ms, \text{Sine half wave}$	132	A
		$T_c=110^{\circ}C, t_p=10ms, \text{Sine half wave}$	106	
Surge repetitive forward current	I_{FRM}	$T_c=25^{\circ}C, t_p=10ms, \text{Sine half wave}$	61	A
I^2t value	$\int I^2t$	$T_c=25^{\circ}C, t_p=10ms, \text{Sine half wave}$	88	A^2s
Total power dissipation	P_D	$T_c=25^{\circ}C$	142	W
		$T_c=110^{\circ}C$	62	
Junction temperature	T_j		175	$^{\circ}C$
Storage temperature	T_{STG}		-55 ~ 175	$^{\circ}C$

Note :

(1) Exceeding these ratings may damage the device.

Thermal Characteristics

Parameter	Symbol	Condition	Typ.	Unit
Thermal resistance	θ_{jc}	Junction - Case	0.9	$^{\circ}C / W$



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Electrical Characteristics

Characteristic	Symbol	Condition	MIN	TYP	MAX	Unit
DC reverse voltage	V_{DC}	$T_j = 25^{\circ}C, I_R = 80\mu A$	650	-	-	V
Forward voltage	V_F	$T_j = 25^{\circ}C, I_F = 16A$	-	1.35	1.5	V
		$T_j = 150^{\circ}C, I_F = 16A$	-	1.6	-	
		$T_j = 175^{\circ}C, I_F = 16A$	-	1.7	-	
Reverse current	I_R	$T_j = 25^{\circ}C, V_R = 650V$	-	3.2	80	uA
		$T_j = 150^{\circ}C, V_R = 650V$	-	12.8	-	
		$T_j = 175^{\circ}C, V_R = 650V$	-	24	-	
Total capacity charge	Q_C	$T_j = 25^{\circ}C, V_R = 400V,$ $di/dt = 350A/us$	-	42	-	nC
Total capacitance	C_{TOT}	$T_j = 25^{\circ}C, V_R = 1V,$ $F = 1MHz$	-	510	-	pF
		$T_j = 25^{\circ}C, V_R = 400V,$ $F = 1MHz$	-	54	-	
		$T_j = 25^{\circ}C, V_R = 650V,$ $F = 1MHz$	-	53	-	
Capacitance Stored Energy	E_C	$V_R = 400V$	-	7	-	μJ



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Electrical Characteristic Curves

V_F – I_F Characteristics

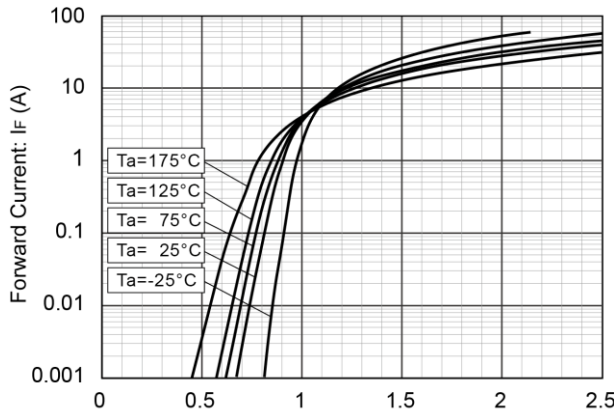


Figure1. Forward Voltage: V_F (V)

V_F – I_F Characteristics

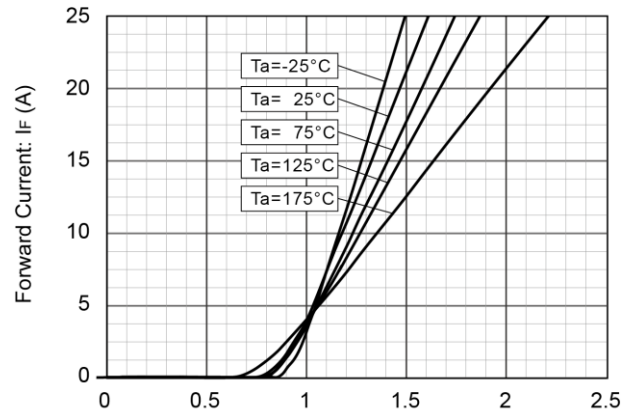


Figure2. Forward Voltage: V_F (V)

V_R – I_R Characteristics

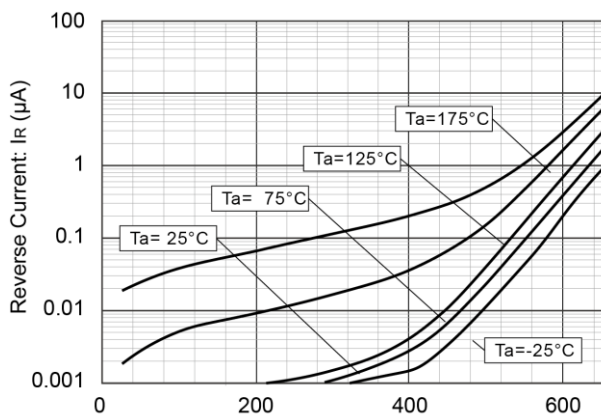


Figure3. Reverse Voltage: V_R (V)

V_R – C_t Characteristics

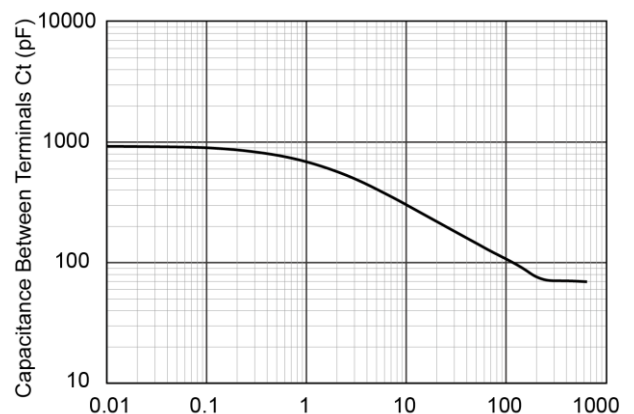


Figure4. Reverse Voltage: V_R(V) Ta = 25 °C f = 1MHz

–Maximum I_P –T_C Characteristics

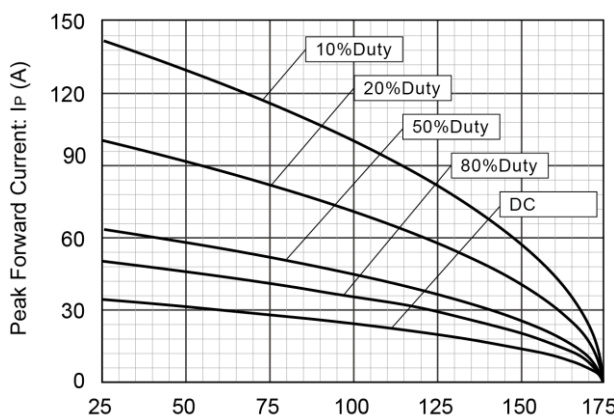


Figure5. Case Temperature: T_C (°C)

Power Dissipation

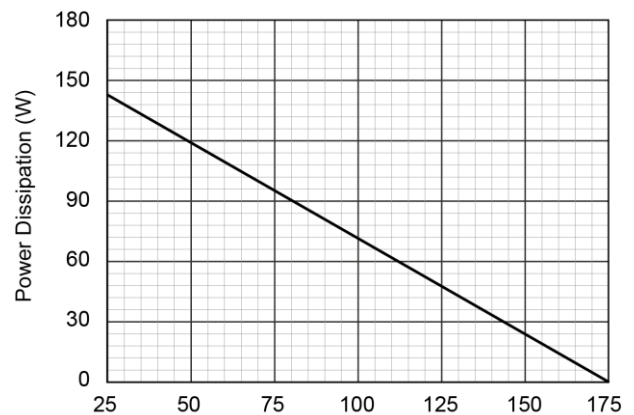
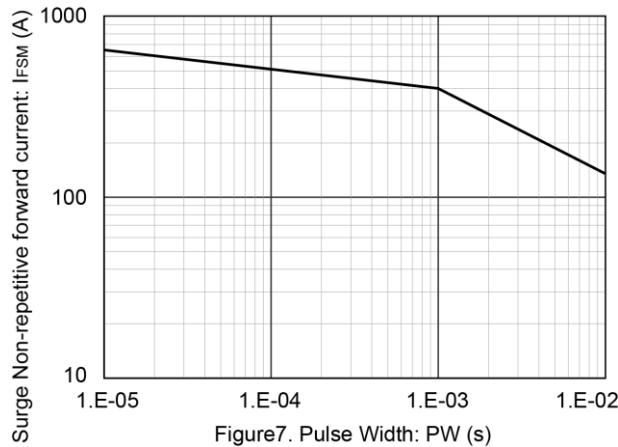


Figure6. Case Temperature: T_C (°C)

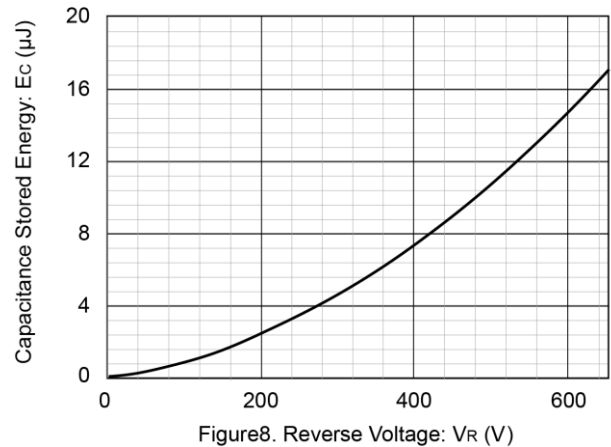


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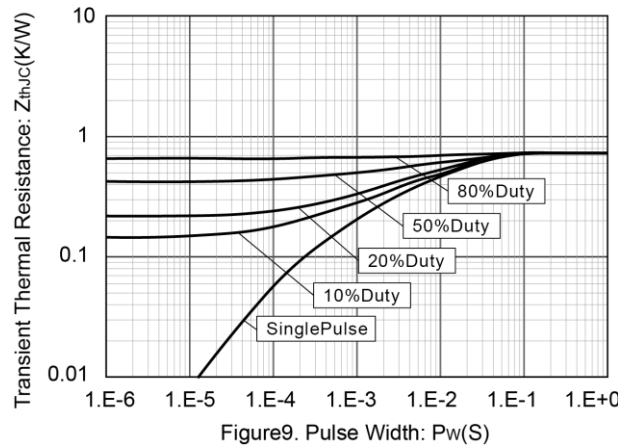
I_{FSM} – PW Characteristics



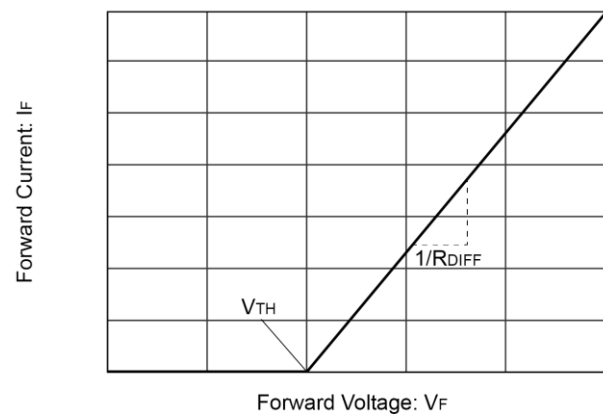
E_C – V_R Characteristics



Typical Transient Thermal Resistance vs. Pulse Width



Simplified Forward Characteristic



$$V_F = V_{TH} + R_{DIFF} \times I_F$$

Threshold Voltage (V_{TH}):

$$V_{TH}(T_j) = -0.002 \times T_j + 0.778 [V]$$

Differential Resistance (R_{DIFF}):

$$R_{DIFF}(T_j) = A \times T_j^2 + B \times T_j + C [\Omega]$$

$$A = 5.0 \times 10^{-7}$$

$$B = 2.0 \times 10^{-4}$$

$$C = 2.91 \times 10^{-2}$$



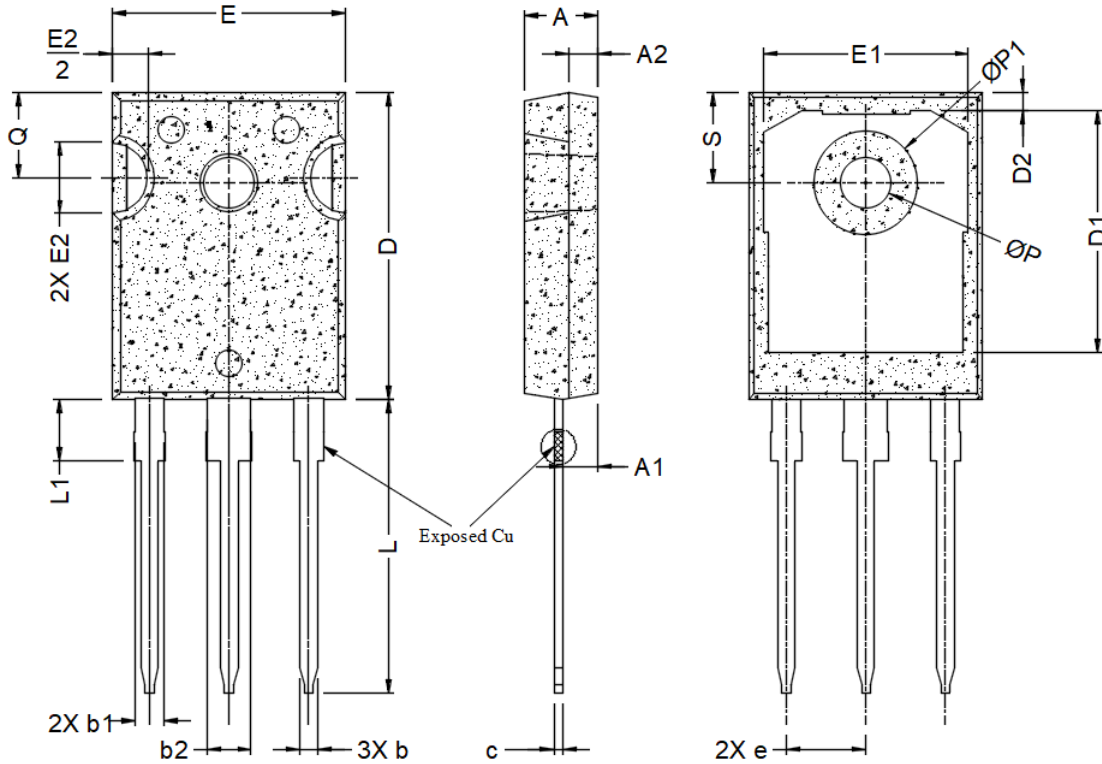
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Package Outline



Unit : mm

SYMBOL	DIMENSIONS		
	MIN.	NCM.	MAX.
A	4.83	5.02	5.21
A1	2.29	2.41	2.55
A2	1.50	2.00	2.49
b	1.12	1.20	1.33
b1	1.91	2.00	2.39
b2	2.87	3.00	3.22
c	0.55	0.60	0.69
D	20.80	20.95	21.10
D1	16.25	16.55	17.65
D2	0.51	1.19	1.35
E	15.75	15.94	16.13
E1	13.46	14.02	14.16
E2	4.32	4.91	5.49
e	5.44BSC		
L	19.81	20.07	20.32
L1	4.10	4.19	4.40
ØP	3.56	3.61	3.65
ØP1	7.19REF.		
Q	5.39	5.79	6.20
S	6.04	6.17	6.30